10/583518 IAP12 Rec'd PCT/PTO 1 6 JUN 2006

Docket No.: 071971-0637 PATENT

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re Application of : Customer Number: 20277

Shunsaku MURAOKA, et al. : Confirmation No.: Not Yet Assigned

Application No.: Not Yet Assigned : Group Art Unit: Not Yet Assigned

Filed: June 16, 2006 : Examiner: Not Yet Assigned

For: METHOD FOR INITIALIZING RESISTANCE-VARIABLE MATERIAL, MEMORY DEVICE CONTAINING A RESISTANCE-VARIABLE MATERIAL, AND METHOD FOR INITIALIZING NONVOLATILE MEMORY CIRCUIT INCLUDING VARIABLE RESISTOR

INFORMATION DISCLOSURE STATEMENT

Commissioner for Patents P.O. Box 1450 Alexandria, VA 22313-1450

Sir:

In accordance with the provisions of 37 C.F.R. 1.56, 1.97 and 1.98, the attention of the Patent and Trademark Office is hereby directed to the references listed on the attached form PTO-1449. It is respectfully requested that the references be expressly considered during the prosecution of this application, and that the references be made of record therein and appear among the "References Cited" on any patent to issue therefrom.

This Information Disclosure Statement is being filed with the application and no certification or fee is required.

A copy of the foreign search report is attached for the Examiner's information. Please note this is a PCT application in the entry of the National Phase in the U.S. and copies of the references cited were transmitted by WIPO and are believed to be in the file of

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the above identified application and readily available to the Examiner. Therefore it is

believed that Applicants have met all requirements regarding duty of disclosure under 37

CFR 1.56. Acknowledgement and consideration of these documents are respectfully

requested.

Since the Search Report was from the EPO search authority, copies of these

references should have been supplied to the USPTO under the trilateral agreement and are

believed to be in the file of the above identified application and readily available to the

Examiner.

Respectfully submitted,

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Please recognize our Customer No. 20277 as our correspondence address.

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SHEET 1 OF 1

INFORMATION DISCLOSURE CITATION IN AN APPLICATION					ATTY. DOCKET NO. 071971-0637	No	SERIAL NO. Not Yet Assigned 10/583518				
					APPLICANT Shunsaku MURAOKA, et al.						
(PTO-1449)					FILING DATE June 16, 2006	GROUP Not Yet Assigned					
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		EXA	AMINER			DATE CONSI	DERED				

^{*}EXAMINER: Initial if reference considered, whether or not citation is in conformance with MPEP 609. Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.

1 Applicant's unique citation designation number (optional). 2 Applicant is to place a check mark here if English language Translation is attached.